

## Ultra-Low Ron with Slew Rate Controlled Load Switch

#### **General Description**

The ET3562 is a small, ultra-low R<sub>ON</sub> load switch with controlled turn on. The device contains a low R<sub>ON</sub> N-Channel MOSFET that can operate over an input voltage range of 1.0 V to 5.5 V and switch currents of up to 3A. An integrated charge pump biases the NMOS switch in order to achieve a low switch ON-Resistance.

The switch is controlled by an on/off input (ON), which is capable of interfacing directly with low-voltage GPIO control signals. An internal reverse voltage comparator disables the power-switch when the output voltage  $(V_{OUT})$  is driven higher than the input voltage  $(V_{IN})$  by  $V_{RCP}$ , to quickly stop the flow of current towards the input side of the switch. Reverse current protection is always active, even when the power-switch is disable.

The ET3562 contains a  $300\Omega$  on-chip load resistor for quick output discharge when the device is turn off.

The ET3562 is available in a small, space-saving WLCSP4 package and is characterized for operation over the free air temperature range of -40°C to 85°C.

#### **Features**

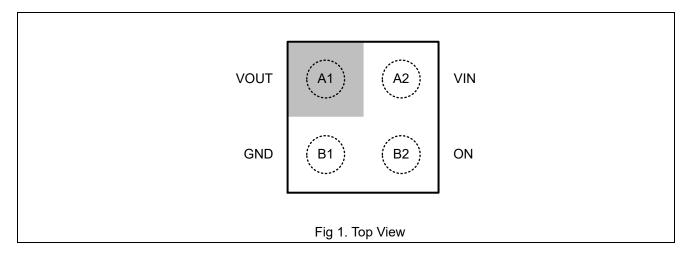
- Input Voltage Range: 1.0V to 5.5V
- Ultra-Low On-Resistance
  - --  $R_{ON} = 35mΩ$  @  $V_{IN} = 5.5V$
  - --  $R_{ON} = 36m\Omega$  @  $V_{IN} = 3.3V$
  - --  $R_{ON} = 37 m\Omega$  @  $V_{IN} = 1.8V$
  - $-- R_{ON} = 49 m\Omega$  @  $V_{IN} = 1.0 V$
- 3A Maximum Continuous Switch Current
- Low Threshold 1.2V GPIO Control Input
- Controlled Slew Rate to Avoid Inrush Current
- ESD Protected: 4kV HBM, 2kV CDM
- Part No. and Package

Part No.	Package	MSL
ET3562	WLCSP4(0.86mm*0.86mm*0.5mm)	Level 1

### **Applications**

- Smartphone
- Notebook Computer and Ultra-book
- Tablet PC Computer
- Solid State Drive (SSD)
- DTV/IP Set Top Box
- POS Terminal and Media Gateway

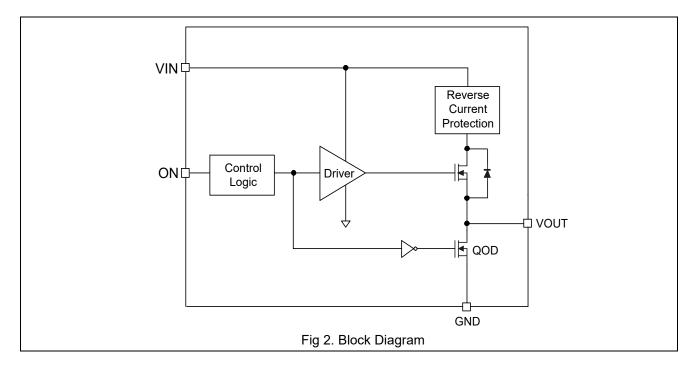
## **Pin Configuration**



## **Pin Function**

Pin	Name	Description
A1	VOUT	Switch Output
A2	VIN	Supply Input: Input to the Power Switch
B1	GND	Ground
B2	ON	ON/OFF Control, Active HIGH Compatible

## **Block Diagram**



#### **Functional Description**

#### **ON/OFF Control**

The ON pin controls the switch. The ON pin is compatible with standard GPIO logic threshold. It can be used with any micro-controller with 1.2V,1.8V,2.5V,3.3V or 5.5V GPIO.

Table 1. Function Table

ON pin state	V <sub>IN</sub> to V <sub>OUT</sub>
L	Off
Н	On

#### **Reverse Current Protection**

The device monitor  $V_{IN}$  and  $V_{OUT}$  voltage levels. When the reverse current voltage threshold (VRCP) is exceeded, the switch is disabled, so as to prevent any reverse current flow to  $V_{IN}$ . This feature is particularly useful when the outputs of ET3562 need to be driven by another voltage source.

#### **Application Information**

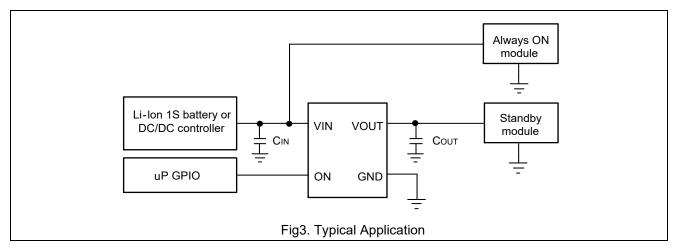
#### **Input Capacitor**

It is recommended to place a capacitor ( $C_{IN}$ ) between VIN and GND pins of ET3562. This capacitor helps to limit the voltage drop on the input voltage supply when the switch turns ON into a discharged load capacitor. A  $1\mu F$  ceramic capacitor that is placed close to the IC pins is usually sufficient. Higher values of  $C_{IN}$  can be used to further reduce the voltage drop in high current applications.

#### **Output Capacitor**

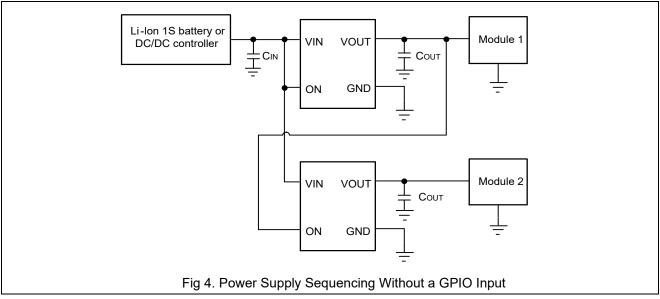
It is recommended to place a capacitor ( $C_{OUT}$ ) between VOUT and GND pins of ET3562. This capacitor acts as a low pass filter along with the switch ON-resistance to remove any voltage glitches coming from the input voltage source. It is generally recommended to have  $C_{IN}$  greater than  $C_{OUT}$  so that once the switch is turned ON,  $C_{OUT}$  can charge up to  $V_{IN}$  without  $V_{IN}$  dropping significantly. A  $0.1\mu F$  ceramic capacitor that is placed close to the IC pins is usually sufficient.

### **Standby Power Reduction**



Any end equipment that is being powered from the battery has a need to reduce current consumption in order to keep the battery charged for a longer time. ET3562 helps to accomplish this by turning off the supply to the modules that are in standby state and hence significantly reduces the leakage current overhead of the standby modules, shows in Fig3.

#### **Power Supply Sequencing Without a GPIO Input**

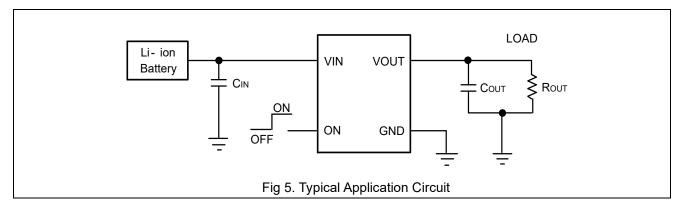


In many end equipments, there is a need to power up various modules in a predetermined manner. ET3562 can solve the problem of power sequencing without adding any complexity to the overall system. Fig4 shows the configuration required for powering up two modules in a fixed sequence. The output of the first load switch is tied to the enable of the second load switch, so when Module 1 is powered the second load switch is enabled and Module 2 is powered.

#### **Typical Application**

ET3562 is an ultra-low ON-resistance, 3A integrated load switch that is capable of interfacing directly with 1S battery in portable consumer devices such as smartphones, tablets etc. Its wide input voltage range (1.0V to 5.5V) makes it suitable to be used for lower voltage rails as well inside different end equipments to accomplish power sequencing, inrush current control and reducing leakage current in subsystems that are in standby mode.

Fig5 shows the typical application circuit of ET3562.



### **Detailed Design Procedure**

#### **Power Supply Recommendations**

The device is designed to operate with a  $V_{IN}$  range of 1.0V to 5.5 V. This supply must be well regulated and placed as close to the device terminal as possible with the recommended 1 $\mu$ F bypass capacitor.

If the supply is located more than a few inches from the device terminals, additional bulk capacitance may be required in addition to the ceramic bypass capacitors. If additional bulk capacitance is required, an electrolytic, tantalum, or ceramic capacitor of 10µF may be sufficient.

### **Absolute Maximum Ratings**

Over operating free-air temperature range (unless otherwise noted)

Symbol	Parameter	Rating	Unit
Vin	Input voltage range	-0.3 to 6.0	V
V <sub>OUT</sub>	Output voltage range	-0.3 to 6.0	V
Von	ON pin voltage range	-0.3 to 6.0	V
I <sub>MAX</sub>	Maximum continuous switch current	3	Α
T <sub>J_MAX</sub>	Maximum junction temperature	150	°C
T <sub>STG</sub>	Storage temperature range	-65 to 150	°C
V <sub>ESD</sub> -	Human-body model (HBM)	±4000	V
	Charged-device model (CDM)	±2000	V

### **Recommended Operating Conditions**

Symbol	Parameter	Min	Max	Unit
VIN	Input voltage range	1.0	5.5	V
Vout	Output voltage range	0	5.5	V
Von	ON pin voltage range		Vin	V
TA	Operating free air temperature range	-40	85	°C
C <sub>IN</sub>	Input capacitor	1 <sup>(1)</sup>		uF

Note1: Refer to the application section

## **Electrical Characteristics**

(Unless otherwise noted,  $V_{IN}$ =1.0 to 5.5V,  $T_A$ =-40 to +85°C; typical values are at  $T_A$ =25°C)

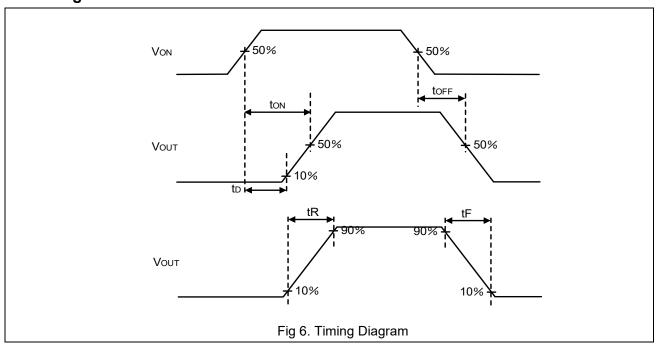
Oh a l	Danamatan	O a a distinua	T <sub>A</sub> = -40°C to 85°C			l loit	
Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
Vin	Input Voltage Range		1.0 <sup>(2)</sup>		5.5	V	
		I <sub>OUT</sub> = 0mA, V <sub>ON</sub> =V <sub>IN</sub> = 5.5V		0.47	5.0		
l	Quiacont Current	$I_{OUT} = 0$ mA, $V_{ON} = V_{IN} = 3.3$ V		0.33	5.0	uA	
I <sub>IN</sub>	Quiescent Current	I <sub>OUT</sub> = 0mA, V <sub>ON</sub> =V <sub>IN</sub> = 1.8V		0.27	5.0	uA	
		I <sub>OUT</sub> = 0mA, V <sub>ON</sub> =V <sub>IN</sub> = 1.0V		0.17	5.0		
		$R_L = 1M\Omega$ , $V_{IN} = 5.5V$ , $V_{ON} = 0V$		0.14	3.0		
	Off accorded Commonst	$R_L = 1M\Omega, V_{IN} = 3.3V, V_{ON} = 0V$		0.08	3.0		
In_off	Off supply Current	$R_L = 1M\Omega$ , $V_{IN} = 1.8V$ , $V_{ON} = 0V$		0.05	3.0	uA	
		$R_L = 1M\Omega$ , $V_{IN} = 1.0V$ , $V_{ON} = 0V$		0.02	3.0		
		V <sub>OUT</sub> =0V, V <sub>IN</sub> = 5.5V, V <sub>ON</sub> = 0V		0.14	3.0		
	Laskana Cumant	V <sub>OUT</sub> =0V, V <sub>IN</sub> = 3.3V, V <sub>ON</sub> = 0V		0.08	3.0		
IIN(Leakage)	Leakage Current	$V_{OUT}=0V, V_{IN}=1.8V, V_{ON}=0V$		0.05	3.0	uA	
		V <sub>OUT</sub> =0V, V <sub>IN</sub> = 1.0V, V <sub>ON</sub> = 0V		0.02	3.0		
	On-Resistance	V <sub>IN</sub> = 5.5V, I <sub>OUT</sub> = -200mA		35	62	0	
D		V <sub>IN</sub> = 3.3V, I <sub>OUT</sub> = -200mA		36	65		
R <sub>ON</sub>		V <sub>IN</sub> = 1.8V, I <sub>OUT</sub> = -200mA		37	65	mΩ	
		V <sub>IN</sub> = 1.0V, I <sub>OUT</sub> = -200mA		49	80		
R <sub>PD</sub>	Output Pull Down Resistance	V <sub>IN</sub> = 3.3V, V <sub>ON</sub> = 0V, V <sub>OUT</sub> = 1.0V		300	500	Ω	
Ion	ON Pin Leakage Current	$V_{IN} = V_{ON} = 1.0V \text{ to } 5.5V$		2	150	nA	
V <sub>RCP</sub>	Reverse Current Voltage Threshold	V <sub>IN</sub> = 1.0V to 5.5V		65	100	mV	
RCP(leak)	Reverse Current Protection Leakage After Reverse Current Event	Vout - VIN>VRCP		0.04	3	uA	
ViH	High-level input voltage, ON	V <sub>IN</sub> = 1.0V to 5.5V	0.9			V	
VıL	Low-level input voltage, ON	V <sub>IN</sub> = 1.0V to 5.5V			0.4	V	

**Note2:** When V<sub>IN</sub> <1.5V,we suppose to set V<sub>ON</sub> ≥1.5V,which can reduce R<sub>ON</sub>.

# **Switching Characteristics**

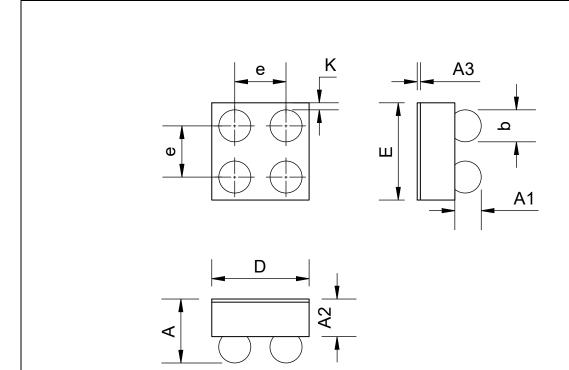
Oh al	Barranatan		T <sub>A</sub> = -40°C to 85°C				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
V <sub>IN</sub> =5.0V,T	$V_{IN}$ =5.0V, $T_A$ = +25°C, unless otherwise noted.						
ton	Turn-On time	$R_L=10\Omega, C_L=0.1uF$	800	1400	1900		
t <sub>OFF</sub>	Turn-Off time	$R_L=10\Omega, C_L=0.1uF$	3	10	20	us	
t <sub>R</sub>	V <sub>OUT</sub> rise time	R <sub>L</sub> =10Ω,C <sub>L</sub> =0.1uF	500	900	1350	us	
t <sub>F</sub>	V <sub>OUT</sub> fall time	$R_L=10\Omega, C_L=0.1uF$	0.5	2.1	10		
V <sub>IN</sub> =3.3V,T	V <sub>IN</sub> =3.3V,T <sub>A</sub> = +25°C, unless otherwise noted.						
ton	Turn-On time	R <sub>L</sub> =10Ω,C <sub>L</sub> =0.1uF	650	1200	1700		
t <sub>OFF</sub>	Turn-Off time	$R_L=10\Omega, C_L=0.1uF$	3	10	20		
t <sub>R</sub>	Vout rise time	R <sub>L</sub> =10Ω,C <sub>L</sub> =0.1uF	400	800	1200	us	
t <sub>F</sub>	V <sub>0∪T</sub> fall time	$R_L=10\Omega, C_L=0.1uF$	0.5	2.1	10		
V <sub>IN</sub> =1.5V,T	$V_{IN}$ =1.5V, $T_A$ = +25°C, unless otherwise noted.						
ton	Turn-On time	$R_L=10\Omega, C_L=0.1uF$	500	1000	1500		
t <sub>OFF</sub>	Turn-Off time	$R_L=10\Omega, C_L=0.1uF$	3	8	20		
t <sub>R</sub>	V <sub>OUT</sub> rise time	$R_L=10\Omega, C_L=0.1uF$	400	800	1500	us	
t <sub>F</sub>	V <sub>0∪T</sub> fall time	$R_L=10\Omega, C_L=0.1uF$	0.5	2.1	10		

# **Switching Waveform**



# **Package Dimension**

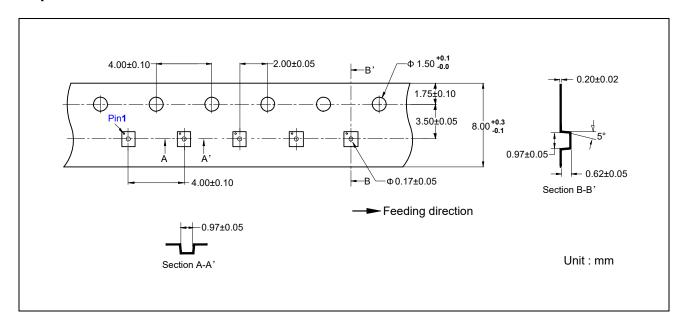
### WLCSP4



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX	
Α	0.447	0.500	0.553	
A1	0.175	0.200	0.225	
A2	0.250	0.275	0.300	
A3	0.022	0.025	0.028	
b	0.240	0.265	0.290	
D	0.830	0.860	0.890	
Е	0.830 0.860 0.890			
е	0.500BSC			
K	0.0475REF			

# Tape



# **Revision History and Checking Table**

Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking
0.0	2023-11-14	Initial Version	Tugz	Luh	Liujy
0.1	2024-01-24	Update EC Table	Tugz	Luh	Liujy
1.0	2024-03-27	Official Version Change V <sub>IN</sub> 1.2V to 1.0V	Tugz	Luh	Liujy